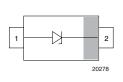


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Vishay Semiconductors

# **Single ESD Protection Diode in SOD-523**





#### **FEATURES**

- Single-line ESD protection
- ESD immunity acc. IEC 61000-4-2
   ± 30 kV contact discharge
   ± 30 kV air discharge
- Typ. capacitance = 130 pF
- Leakage current I<sub>R</sub> < 1 μA (V<sub>R</sub> = 5 V)
- e3 Sn
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912







#### **MARKING** (example only)



Bar = cathode marking X = date code

Y = type code (see table below)

#### **ADDITIONAL RESOURCES**



ORDERING INFORMATION					
DEVICE NAME	ORDERING CODE	TAPED UNITS PER REEL	MINIMUM ORDER QUANTITY		
VESD05A1-02V	VESD05A1-02V-G-08	3000 (8 mm tape on 7" reel)	3000		
	VESD05A1-02V-G-18	10 000 (8 mm tape on 13" reel)	10 000		

PACKAGE DATA						
DEVICE NAME	PACKAGE NAME	TYPE CODE	WEIGHT	MOLDING COMPOUND FLAMMABILITY RATING	MOISTURE SENSITIVITY LEVEL	SOLDERING CONDITIONS
VESD05A1-02V (-G-08 / -G-18)	SOD-523	. Н	1.35 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	Peak temperature max. 260 °C

ABSOLUTE MAXIMUM RATINGS VESD05A1-02V						
PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT		
Peak pulse current	Acc. IEC 61000-4-5, 8/20 μs/single shot	I <sub>PPM</sub>	16	Α		
Peak pulse power	Acc. IEC 61000-4-5, 8/20 μs/single shot	P <sub>PP</sub>	192	W		
FCD iit	Contact discharge acc. IEC 61000-4-2; 10 pulses	V	± 30	kV		
ESD immunity	Air discharge acc. IEC 61000-4-2; 10 pulses	acc. IEC 61000-4-2; 10 pulses	± 30	kV		
Operating temperature	Junction temperature	TJ	-40 to +125	°C		
Storage temperature		T <sub>stg</sub>	-55 to +150	°C		



# VESD05A1-02V (-G-08 / -G-18)

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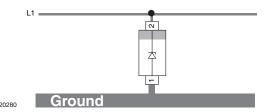
#### **BiAs-MODE** (bidirectional asymmetrical protection mode)

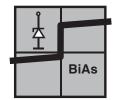
With the VESD05A1-02V one signal- or data-lines (L1) can be protected against voltage transients. With pin 1 connected to ground and pin 2 connected to a signal- or data-line which has to be protected. As long as the voltage level on the data- or signal-line is between 0 V (ground level) and the specified maximum reverse working voltage (V<sub>RWM</sub>) the protection diode between data line and ground offers a high isolation to the ground line. The protection device behaves like an open switch. As soon as any positive transient voltage signal exceeds the break through voltage level of the protection diode, the diode

As soon as any positive transient voltage signal exceeds the break through voltage level of the protection diode, the diode becomes conductive and shorts the transient current to ground. Now the protection device behaves like a closed switch. The clamping voltage  $(V_C)$  is defined by the breakthrough voltage  $(V_{BR})$  level plus the voltage drop at the series impedance (resistance and inductance) of the protection device.

Any negative transient signal will be clamped accordingly. The negative transient current is flowing in the forward direction of the protection diode. The low forward voltage (V<sub>F</sub>) clamps the negative transient close to the ground level.

Due to the different clamping levels in forward and reverse direction the VESD05A1-02V clamping behavior is bidirectional and asymmetrical (BiAs).





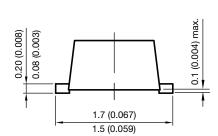
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Protection paths	Number of lines which can be protected	N <sub>channel</sub>	-	-	1	lines
Reverse stand off voltage	Max. reverse working voltage	$V_{RWM}$	-	-	5	V
Reverse voltage	at I <sub>R</sub> = 1 μA	$V_R$	5	-	-	V
Reverse current	at V <sub>R</sub> = 5 V	I <sub>R</sub>	-	< 0.1	1	μA
Reverse breakdown voltage	at I <sub>R</sub> = 1 mA	$V_{BR}$	6	6.8	7.5	V
Reverse clamping voltage	at I <sub>PP</sub> = 1 A; 8/20 µs test pulse	V <sub>C</sub>	-	7.2	8.5	V
	at I <sub>PP</sub> = I <sub>PPM</sub> = 16 A; 8/20 µs test pulse	$V_{C}$	-	10.5	12	V
Forward clamping voltage	at I <sub>PP</sub> = 0.2 A; 8/20 µs test pulse	$V_{F}$	-	0.88	1.1	V
	at I <sub>PP</sub> = 1 A; 8/20 µs test pulse	$V_{F}$	-	1	1.5	V
	at I <sub>PP</sub> = I <sub>PPM</sub> = 16 A; 8/20 µs test pulse	$V_{F}$	-	3.2	4.5	V
Capacitance	at V <sub>R</sub> = 0 V; f = 1 MHz	$C_D$	-	130	150	pF
	at V <sub>B</sub> = 2.5 V; f = 1 MHz	C <sub>D</sub>	-	76	-	pF

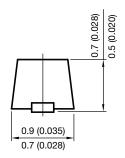


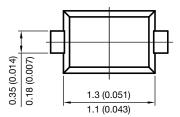
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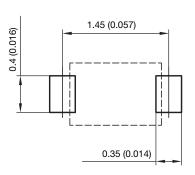
#### PACKAGE DIMENSIONS in millimeters (Inches): SOD-523







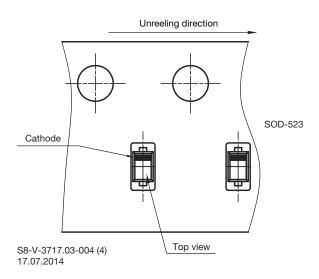
foot print recommendation:



Document no.: S8-V-3880.02-001 (4)

Rev. h - Date: 13. Oct. 2010

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